

# NPN SILICON RF TRANSISTOR NE856M02 / 2SC5336 JEITA Part No.

### NPN SILICON RF TRANSISTOR FOR HIGH-FREQUENCY LOW DISTORTION AMPLIFIER 4-PIN POWER MINIMOLD

#### **FEATURES**

- High gain:  $|S_{21e}|^2 = 12 \text{ dB TYP.}$  @ VcE = 10 V, Ic = 20 mA, f = 1 GHz
- 4-pin power minimold package with improved gain from the NE85634 / 2SC3357

#### **★ ORDERING INFORMATION**

Part Number	Quantity	Supplying Form			
NE856M02-AZ	25 pcs (Non reel)	Magazine case			
2SC5336-AZ		12 mm wide embossed taping			
NE856M02-AZ 2SC5336-T1-AZ	1 kpcs/reel	Collector face the perforation side of the tape			

**Remark** To order evaluation samples, please contact your nearby sales office. Unit sample quantity is 25 pcs.

### ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	20	V
Collector to Emitter Voltage	VCEO	12	V
Emitter to Base Voltage	VEBO	3.0	٧
Collector Current	lc	100	mA
Total Power Dissipation	Ptot Note	ot Note 1.2	
Junction Temperature	Tj	150	°C
Storage Temperature	T <sub>stg</sub>	-65 to +150	°C

**Note** Mounted on 16 cm $^2 \times 0.7$  mm (t) ceramic substrate (Copper plating)

Because this product uses high-frequency technology, avoid excessive static electricity, etc.

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### **ELECTRICAL CHARACTERISTICS (TA = +25°C)**

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	Ісво	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0 mA	-	-	1.0	μΑ
Emitter Cut-off Current	ІЕВО	V <sub>BE</sub> = 1 V, Ic = 0 mA	-	-	1.0	μΑ
DC Current Gain	hfE Note 1	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 20 mA	50	120	250	-
RF Characteristics						
Gain Bandwidth Product	f⊤	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 20 mA	_	6.5	-	GHz
Insertion Power Gain	S <sub>21e</sub>   <sup>2</sup>	Vce = 10 V, Ic = 20 mA, f = 1 GHz	_	12	1	dB
Noise Figure (1)	NF	Vce = 10 V, Ic = 7 mA, f = 1 GHz	-	1.1	-	dB
Noise Figure (2)	NF	Vce = 10 V, Ic = 40 mA, f = 1 GHz	-	1.8	3.0	dB
Reverse Transfer Capacitance	Cre Note 2	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0 mA, f = 1 MHz	-	0.5	0.8	pF

**Notes 1.** Pulse measurement: PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2%

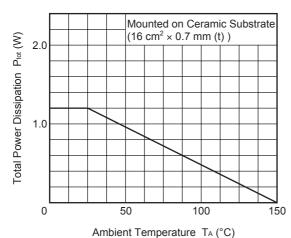
2. Collector to base capacitance when the emitter grounded

#### **hfe CLASSIFICATION**

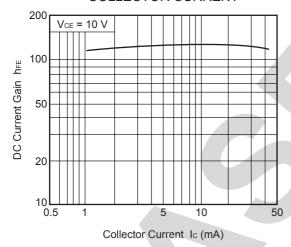
Rank	RH	RF	RE
Marking	RH	RF	RE
h <sub>FE</sub> Value	50 to 100	80 to 160	125 to 250

#### **★ TYPICAL CHARACTERISTICS (Unless otherwise specified, TA = +25°C)**

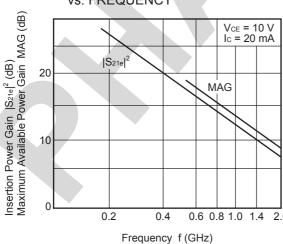




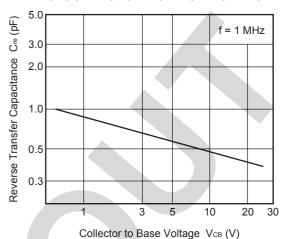
## DC CURRENT GAIN vs. COLLECTOR CURRENT



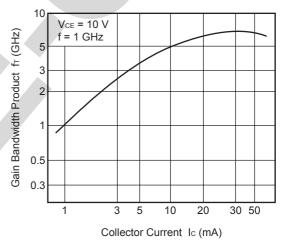
### INSERTION POWER GAIN, MAG vs. FREQUENCY



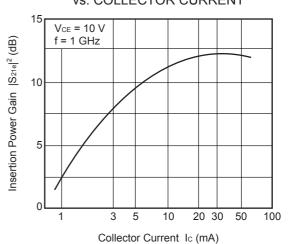
### REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE

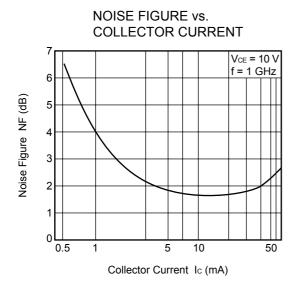


### GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT

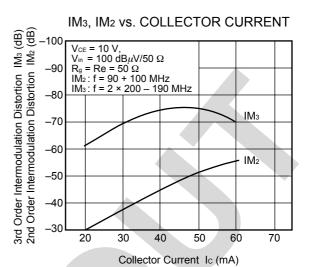


### INSERTION POWER GAIN vs. COLLECTOR CURRENT





Remark The graphs indicate nominal characteristics.



### **S-PARAMETERS**

$V_{CE} = 1$	0 V.	Ic = 20	mΑ
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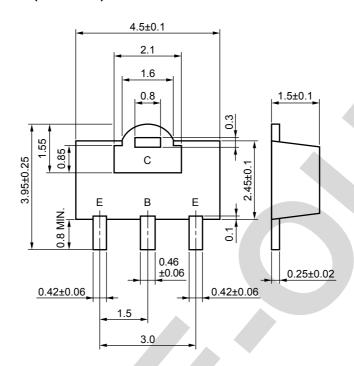
Frequency	5	S <sub>11</sub>	S	21	S.	12	Sa	22
(GHz)	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.
		(deg.)		(deg.)		(deg.)		(deg.)
0.1	0.519	-74.5	30.931	131.9	0.017	60.6	0.752	-30.2
0.2	0.413	-112.9	18.965	111.5	0.031	61.9	0.570	-39.7
0.3	0.413	-133.4	13.324	101.9	0.038	65.1	0.465	-39.8
0.4	0.345	-145.7	10.164	95.9	0.045	69.8	0.428	-40.1
0.5	0.331	-153.8	8.177	91.8	0.055	71.8	0.436	-41.1
0.6	0.320	-159.6	6.834	89.1	0.064	70.9	0.438	-43.5
0.7	0.302	-166.8	5.832	86.7	0.074	73.9	0.434	-47.5
8.0	0.296	-169.2	5.107	84.3	0.077	74.4	0.429	-47.8
0.9	0.283	-173.2	4.600	83.1	0.088	71.2	0.436	-46.5
1.0	0.285	-179.8	4.200	82.3	0.097	74.5	0.455	-47.8
1.1	0.265	175.2	3.930	8.08	0.100	76.3	0.467	-46.8
1.2	0.260	174.1	3.979	78.5	0.109	75.9	0.529	-47.4
1.3	0.263	166.0	3.741	68.6	0.114	76.8	0.551	-55.8
1.4	0.242	163.0	3.115	66.6	0.119	78.3	0.509	-55.8
1.5	0.252	160.1	2.844	65.7	0.133	82.0	0.510	-58.5
1.6	0.253	154.0	2.595	64.1	0.140	81.0	0.496	-55.2
1.7	0.253	149.9	2.420	63.7	0.158	80.9	0.515	-54.8
1.8	0.257	147.2	2.305	63.0	0.165	82.2	0.518	-56.5
1.9	0.262	143.0	2.171	62.6	0.172	80.5	0.536	-58.6
2.0	0.273	141.5	2.049	61.2	0.177	78.3	0.524	-61.5

 $V_{CE} = 10 \text{ V}, \text{ Ic} = 40 \text{ mA}$ 

102 101,10								
Frequency		S <sub>11</sub>	S	21	s	12	S	22
(GHz)	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.
		(deg.)		(deg.)		(deg.)		(deg.)
0.1	0.378	-97.1	32.908	123.3	0.017	71.1	0.665	-34.7
0.2	0.317	-131.8	18.819	106.0	0.027	71.2	0.487	-38.7
0.3	0.308	-150.1	12.955	97.5	0.035	71.8	0.398	-38.5
0.4	0.299	-158.7	9.775	93.1	0.042	78.1	0.393	-36.9
0.5	0.297	-165.5	7.899	89.8	0.052	78.5	0.399	-37.6
0.6	0.288	-169.2	6.586	87.6	0.061	79.1	0.407	-39.9
0.7	0.274	-173.7	5.607	85.2	0.071	77.4	0.400	-44.6
0.8	0.261	-177.3	4.879	83.5	0.081	76.4	0.415	-47.4
0.9	0.255	178.9	4.435	82.2	0.092	76.5	0.399	-46.2
1.0	0.260	173.0	4.024	81.4	0.095	77.6	0.440	-44.3
1.1	0.243	169.4	3.801	80.6	0.098	77.1	0.441	-45.2
1.2	0.239	169.3	3.827	78.2	0.109	78.3	0.494	-46.2
1.3	0.245	160.3	3.587	68.4	0.117	78.0	0.517	-55.4
1.4	0.216	157.8	2.980	66.0	0.125	80.3	0.486	-54.5
1.5	0.235	155.3	2.726	66.1	0.137	86.5	0.500	-59.0
1.6	0.243	148.8	2.537	64.0	0.143	80.6	0.474	-53.7
1.7	0.233	146.0	2.348	64.2	0.159	81.2	0.496	-56.8
1.8	0.242	144.6	2.200	63.5	0.163	80.4	0.491	-53.6
1.9	0.249	141.9	2.073	63.3	0.171	81.7	0.534	-58.0
2.0	0.260	140.4	1.986	61.7	0.184	77.5	0.535	-61.3

### **★ PACKAGE DIMENSIONS**

### 4-PIN POWER MINIMOLD (UNIT: mm)



### **PIN CONNECTIONS**

E: Emitter

C: Collector

B: Base

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